

**TC74AC164P, TC74AC164F, TC74AC164FN, TC74AC164FT****8 - BIT SHIFT REGISTER (S - IN, P - OUT)**

The TC74AC164 is an advanced high speed CMOS 8 - BIT SERIAL - IN PARALLEL - OUT SHIFT REGISTER fabricated with silicon gate and double - layer metal wiring C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It consists of a serial - in, parallel - out 8 - bit shift register with a CLOCK input and an overriding CLEAR input.

Two serial data inputs (A, B) are provided so that one may be used as a data enable.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

**FEATURES :**

- High Speed..... $f_{MAX} = 170\text{MHz}$  (typ.) at  $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 8\mu\text{A}$ (Max.) at  $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (Min.)
- Symmetrical Output Impedance..... $|I_{OH}| = I_{OL} = 24\text{mA}$ (Min.)  
Capability of driving  $50\Omega$  transmission lines.
- Balanced Propagation Delays..... $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range.... $V_{CC}$  (opr) =  $2\text{V} \sim 5.5\text{V}$
- Pin and Function Compatible with 74F164

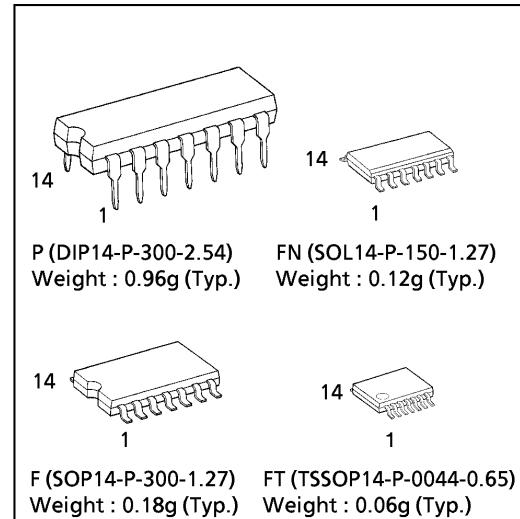
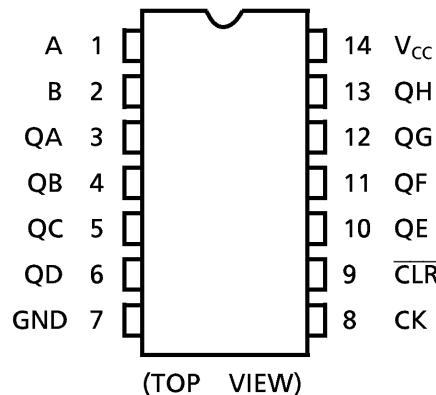
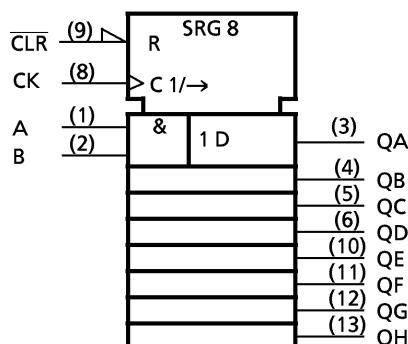
**TRUTH TABLE**

INPUTS			OUTPUTS					
CLR	CK	SERIAL IN		QA	QB	...	QH	
		A	B					
L	X	X	X	L	L	...	L	
H		X	X	NO CHANGE				
H		L	X	L	$QA_n$	...	$QG_n$	
H		X	L	L	$QA_n$	...	$QG_n$	
H		H	H	H	$QA_n$	...	$QG_n$	

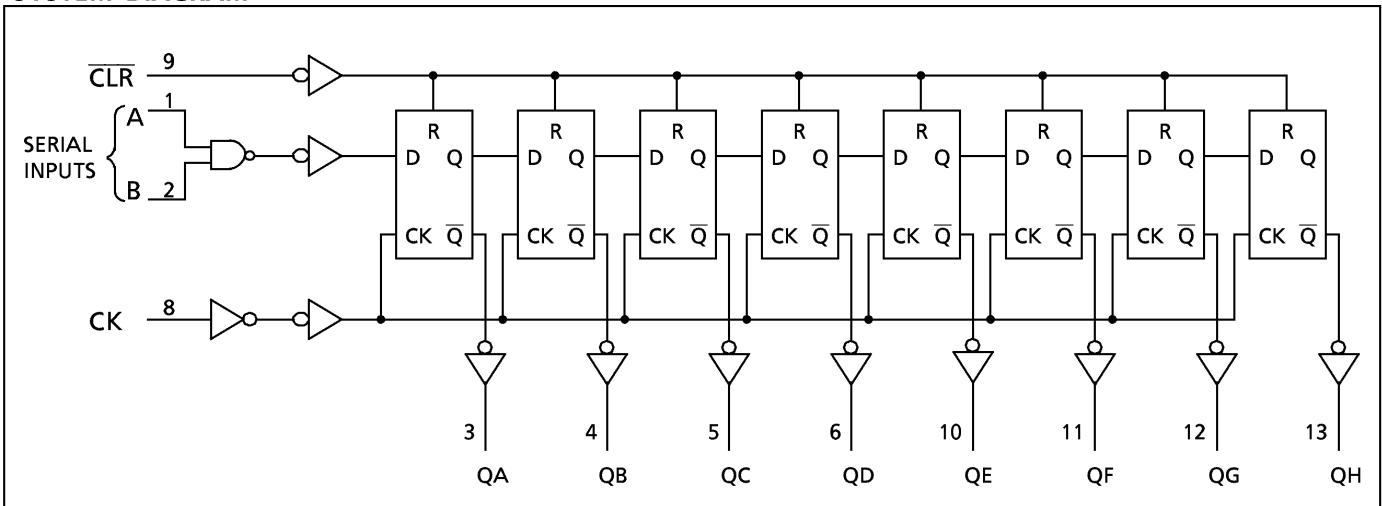
X : Don't Care

$QA_n \sim QG_n$ : The level of  $QA \sim QG$ , respectively, before the most recent positive edge of the clock.

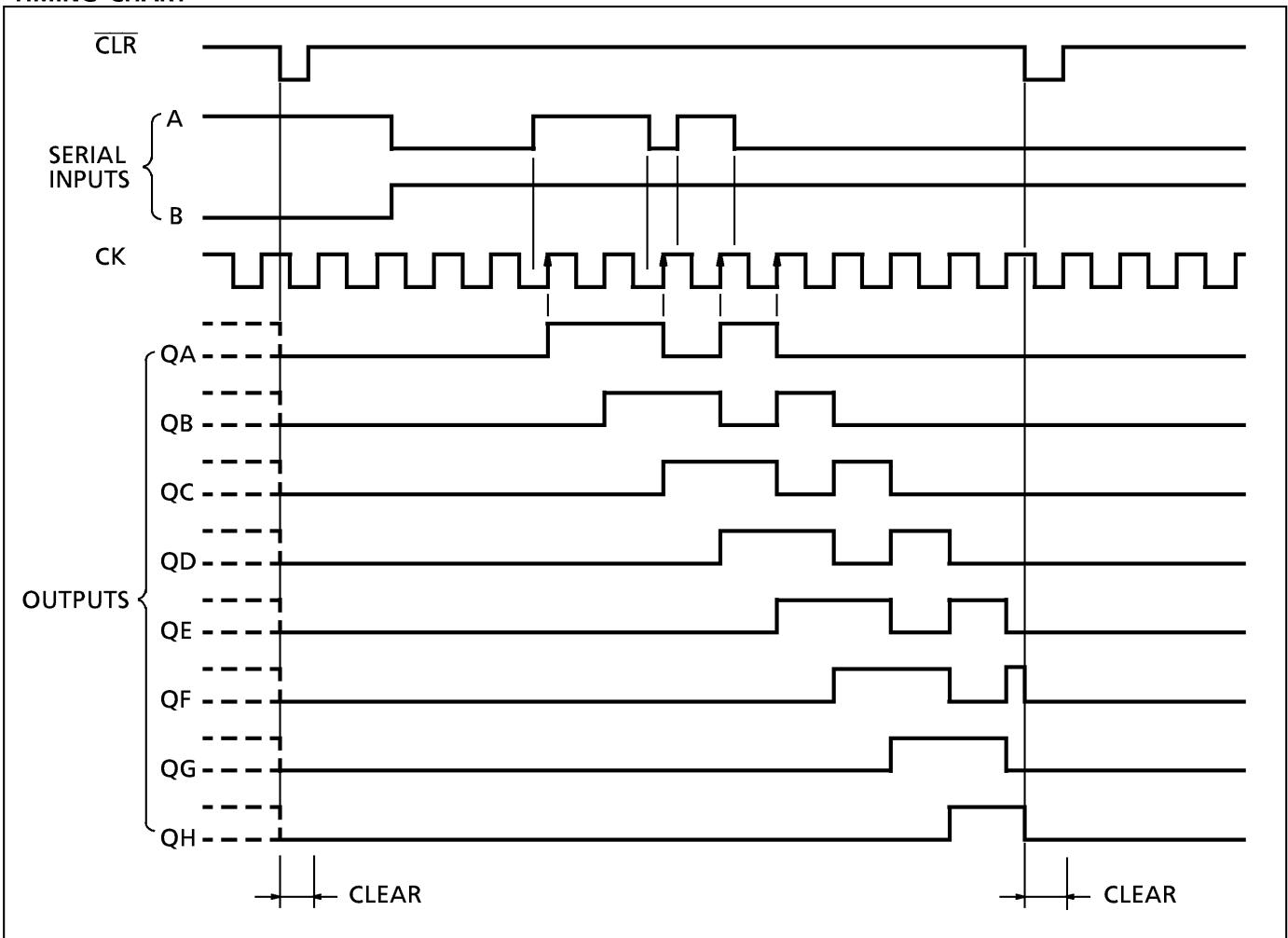
(Note) The JEDEC SOP (FN) is not available in Japan.

**PIN ASSIGNMENT****IEC LOGIC SYMBOL**

## SYSTEM DIAGRAM



## TIMING CHART



## ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7.0	V
DC Input Voltage	$V_{IN}$	-0.5~ $V_{CC}$ + 0.5	V
DC Output Voltage	$V_{OUT}$	-0.5~ $V_{CC}$ + 0.5	V
Input Diode Current	$I_{IK}$	$\pm 20$	mA
Output Diode Current	$I_{OK}$	$\pm 50$	mA
DC Output Current	$I_{OUT}$	$\pm 50$	mA
DC $V_{CC}$ /Ground Current	$I_{CC}$	$\pm 200$	mA
Power Dissipation	$P_D$	500 (DIP)*/ 180 (SOP/TSSOP)	mW
Storage Temperature	$T_{STG}$	-65~150	°C

\*500mW in the range of  $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$ . From  $T_a = 65^{\circ}\text{C}$  to  $85^{\circ}\text{C}$  a derating factor of  $-10\text{mW}/^{\circ}\text{C}$  should be applied up to 300mW.

## RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	2.0~5.5	V
Input Voltage	$V_{IN}$	0~ $V_{CC}$	V
Output Voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise and Fall Time	$dt/dV$	0~ 100 ( $V_{CC} = 3.3 \pm 0.3\text{V}$ ) 0~ 20 ( $V_{CC} = 5 \pm 0.5\text{V}$ )	ns/V

## DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	Ta = 25°C			Ta = -40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	$V_{IH}$		2.0	1.50	—	—	1.50	—	V
			3.0	2.10	—	—	2.10	—	
			5.5	3.85	—	—	3.85	—	
Low - Level Input Voltage	$V_{IL}$		2.0	—	—	0.50	—	0.50	V
			3.0	—	—	0.90	—	0.90	
			5.5	—	—	1.65	—	1.65	
High - Level Output Voltage	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -50\mu\text{A}$	2.0	1.9	2.0	—	1.9	V
			$I_{OH} = -4\text{mA}$	3.0	2.9	3.0	—	2.9	
			$I_{OH} = -24\text{mA}$	4.5	4.4	4.5	—	4.4	
Low - Level Output Voltage	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -75\text{mA}^*$	3.0	2.58	—	—	2.48	V
			$I_{OL} = 50\mu\text{A}$	4.5	3.94	—	—	3.80	
			$I_{OL} = 12\text{mA}$	5.5	—	—	—	3.85	
Input Leakage Current	$I_{IN}$	$V_{IN} = V_{CC}$ or GND	2.0	—	0.0	0.1	—	0.1	$\mu\text{A}$
			3.0	—	0.0	0.1	—	0.1	
			4.5	—	0.0	0.1	—	0.1	
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	3.0	—	—	0.36	—	0.44	$\mu\text{A}$
			4.5	—	—	0.36	—	0.44	
			5.5	—	—	—	—	1.65	

\* : This spec indicates the capability of driving  $50\Omega$  transmission lines.

One output should be tested at a time for a 10ms maximum duration.

TIMING REQUIREMENTS ( Input  $t_r = t_f = 3\text{ns}$  )

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	$T_a = 25^\circ\text{C}$	$T_a = -40\text{--}85^\circ\text{C}$	UNIT
				LIMIT	LIMIT	
Minimum Pulse Width ( CK )	$t_W(L)$ $t_W(H)$		$3.3 \pm 0.3$	9.0	10.0	ns
			$5.0 \pm 0.5$	5.0	6.0	
Minimum Pulse Width ( CLR )	$t_W(L)$		$3.3 \pm 0.3$	9.0	10.0	
			$5.0 \pm 0.5$	5.0	6.0	
Minimum Set-up Time	$t_s$		$3.3 \pm 0.3$	7.0	7.0	
			$5.0 \pm 0.5$	4.0	4.0	
Minimum Hold Time	$t_h$		$3.3 \pm 0.3$	1.0	1.0	
			$5.0 \pm 0.5$	1.0	1.0	
Minimum Removal Time ( CLR )	$t_{rem}$		$3.3 \pm 0.3$	8.5	8.5	
			$5.0 \pm 0.5$	5.0	5.0	

AC ELECTRICAL CHARACTERISTICS ( $C_L = 50\text{pF}$ ,  $R_L = 500\Omega$ , Input  $t_r = t_f = 3\text{ns}$ )

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	$T_a = 25^\circ\text{C}$			$T_a = -40\text{--}85^\circ\text{C}$		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time ( CK-Q )	$t_{pLH}$ $t_{pHL}$		$3.3 \pm 0.3$	—	9.6	16.3	1.0	18.6	ns
			$5.0 \pm 0.5$	—	6.6	9.8	1.0	11.2	
Propagation Delay Time ( CLR-Q )	$t_{pHL}$		$3.3 \pm 0.3$	—	8.0	15.4	1.0	17.5	
			$5.0 \pm 0.5$	—	6.0	11.0	1.0	12.5	
Maximum Clock Frequency	$f_{MAX}$		$3.3 \pm 0.3$	45	100	—	45	—	MHz
Input Capacitance	$C_{IN}$			—	5	10	—	10	pF
Power Dissipation Capacitance	$C_{PD}(1)$			—	110	—	—	—	

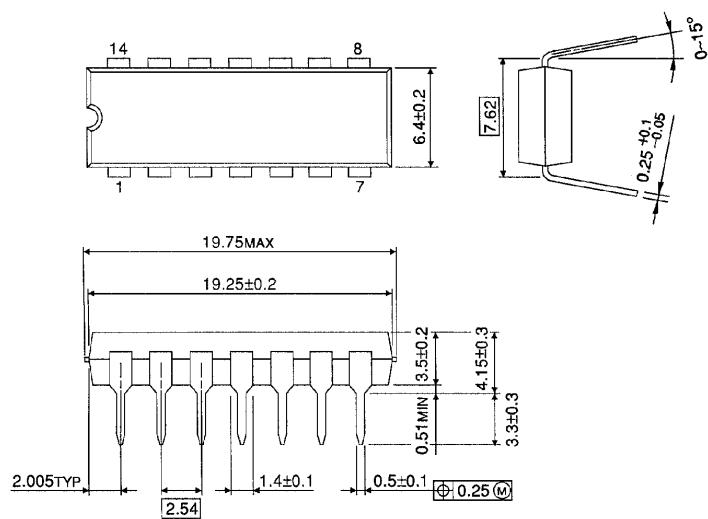
Note (1)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

## DIP 14PIN PACKAGE DIMENSIONS (DIP14-P-300-2.54)

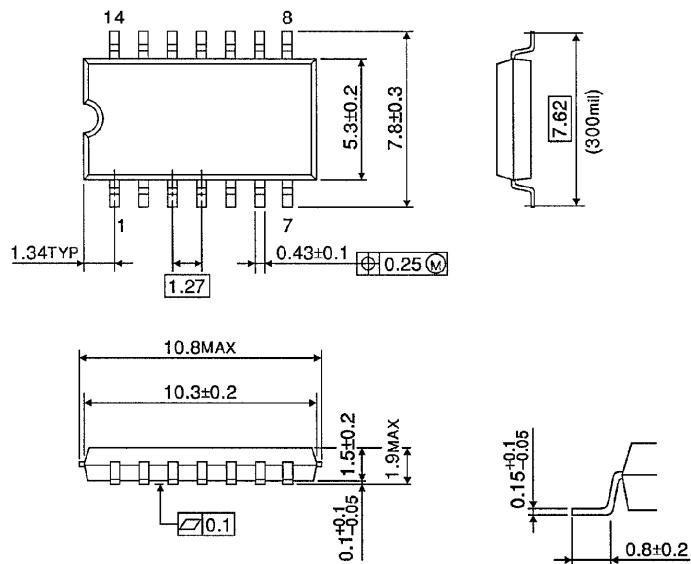
Unit in mm



Weight : 0.96g (Typ.)

## SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)

Unit in mm

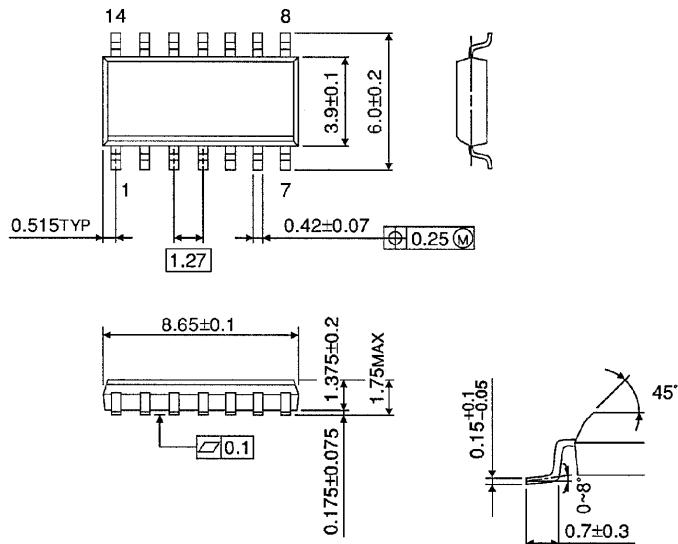


Weight : 0.18g (Typ.)

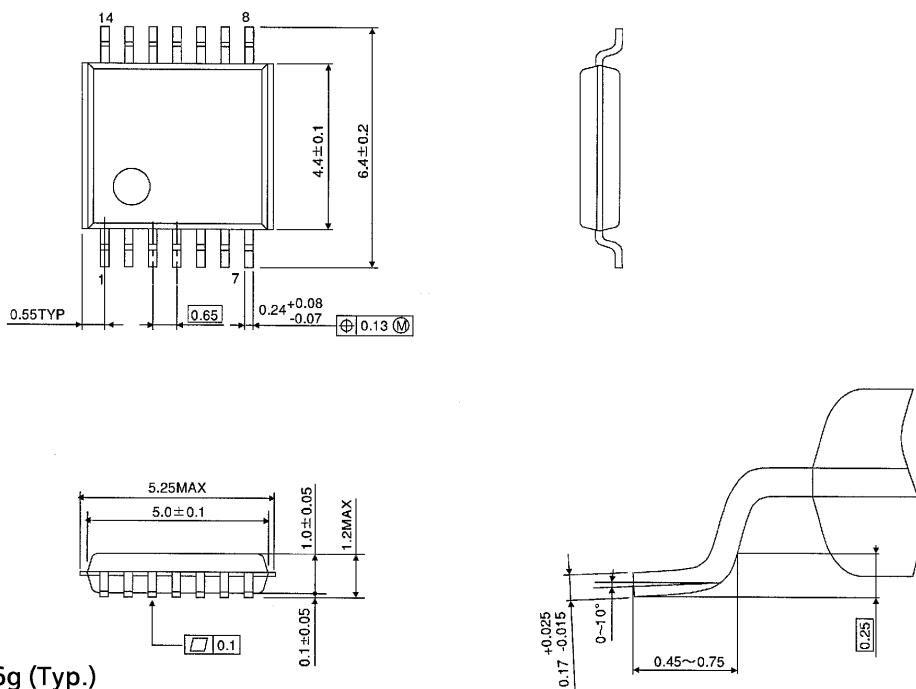
**SOP 14PIN (150mil BODY) PACKAGE DIMENSIONS (SOL14-P-150 -1.27)**

Unit in mm

(Note) This package is not available in Japan.

**TSSOP 14PIN (170mil BODY) PACKAGE DIMENSIONS (TSSOP14-P-0044-0.65)**

Unit in mm



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000707EBA

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